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	Filing Date		2006-06-07	
	First Named Inventor	Tetsuo Fujii		
	Art Unit	2815		
	Examiner Name	Jerome Jackson Jr.		
	Attorney Docket Number	G&C 30794.108-US-WO		

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	1	Palacios, T. et al., "Wet Etching of GaN Grown by Molecular Beam Epitaxy on Si (111)"; Semiconductor Science and Technology, IOP, Bristol, GB, Vol. 15, No. 10, October 2000, Pages 96-1000, XP000976071.	<input type="checkbox"/>
	2	Chu, Chen-Fu et al.; "Comparison of P-Side Down and P-Side Up GaN Light-Emitting Diodes Fabricated by Laser Lift-Off", Japanese Journal of Applied Physics, Japan Society of Applied Physics, Tokyo, JP, Vol. 42, No. 2B, Part 2, February 15, 2003, Pages L147-L150, XP001192476.	<input type="checkbox"/>
	3	Ng, Hock M. et al., "Patterning GaN Microstructures by Polarity-Selective Chemical Etching", Japanese Journal of Applied Physics, Japan Society of Applied Physics, Tokyo, JP, Vol. 42, No. 12A, Part 2, December 1, 2003, Pages L1405-L1407, XP001186585.	<input type="checkbox"/>
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